RoHS



## Vishay General Semiconductor

# **Ultrafast Avalanche SMD Rectifier**



**DO-214AC (SMA)** 

PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub>	1.5 A		
$V_{RRM}$	1000 V		
I <sub>FSM</sub>	30 A		
I <sub>R</sub>	5.0 μΑ		
t <sub>rr</sub>	75 ns		
V <sub>F</sub>	1.7 V		
E <sub>R</sub>	20 mJ		
T <sub>J</sub> max.	150 °C		
Package	DO-214AC (SMA)		
Diode variations	Single die		

#### **FEATURES**

- Low profile package
- · Ideal for automated placement
- · Glass passivated pellet chip junction
- Low reverse current
- High reverse voltage
- Ultra fast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer, automotive and telecommunication.

### **MECHANICAL DATA**

Case: DO-214AC (SMA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 2 whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	BYG23M	UNIT	
Device marking code		BYG23M		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	1000	V	
Average forward current at T <sub>A</sub> = 65 °C	I <sub>F(AV)</sub>	1.5	Α	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30	А	
Pulse energy in avalanche mode, non repetitive (inductive load switch off) I <sub>(BR)R</sub> = 1 A, T <sub>J</sub> = 25 °C	E <sub>R</sub>	20	mJ	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	BYG23M	UNIT	
Minimum breakdown voltage	I <sub>R</sub> = 100 μA		$V_{BR}$	1000	V	
Maximum instantaneous voltage	I <sub>E</sub> = 1.0 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	1.7	V	
		T <sub>J</sub> = 150 °C		1.35	]	
Maximum reverse current	V V	T <sub>J</sub> = 25 °C	I <sub>R</sub>	5	μΑ	
	$V_R = V_{RRM}$	T <sub>J</sub> = 125 °C		50		
Maximum reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> =	1.0 A, I <sub>rr</sub> = 0.25 A	t <sub>rr</sub>	75	ns	

#### Note

 $<sup>^{(1)}</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	BYG23M	UNIT
Typical thermal resistance, junction to case	$R_{ heta JC}$	25	°C/W
	R <sub>0JA</sub> <sup>(1)</sup>	150	
Typical thermal resistance, junction to ambient	R <sub>0</sub> JA (2)	125	°C/W
	R <sub>0</sub> JA (3)	100	

### Notes

- $^{(1)}$  Mounted on epoxy-glass hard tissue, 17 mm<sup>2</sup> 35  $\mu$ m Cu
- (2) Mounted on epoxy-glass hard tissue, 50 mm<sup>2</sup> 35 μm Cu
- (3) Mounted on Al-oxide-ceramic (Al<sub>2</sub>O<sub>3</sub>), 50 mm<sup>2</sup> 35 μm Cu

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QANTITY	DELIVERY MODE	
BYG23M-E3/TR	0.064	TR	1800	7" diameter plastic tape and reel	
BYG23M-E3/TR3	0.064	TR3	7500	13" diameter plastic tape and reel	
BYG23MHE3/TR (1)	0.064	TR	1800	7" diameter plastic tape and reel	
BYG23MHE3/TR3 (1)	0.064	TR3	7500	13" diameter plastic tape and reel	

### Note

<sup>(1)</sup> AEC-Q101 qualified

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## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

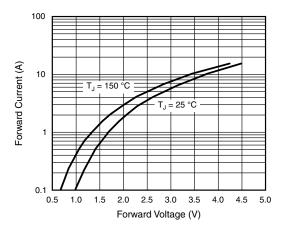


Fig. 1 - Max. Forward Current vs. Forward Voltage

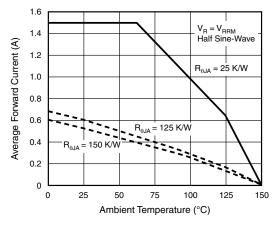


Fig. 2 - Max. Average Forward Current vs. Ambient Temperature

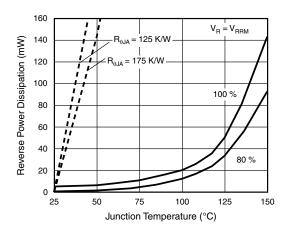


Fig. 3 - Max. Reverse Power Dissipation vs. Junction Temperature

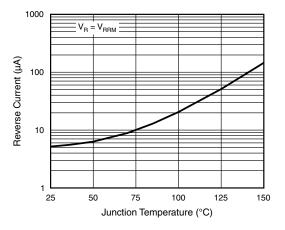


Fig. 4 - Reverse Current vs. Junction Temperature

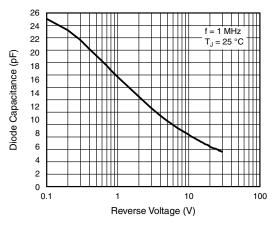


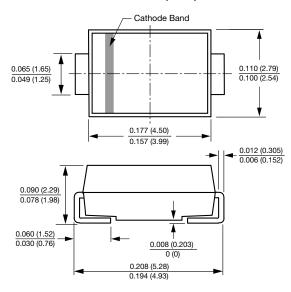
Fig. 5 - Diode Capacitance vs. Reverse Voltage



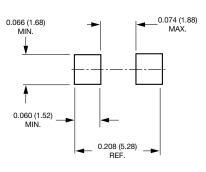
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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### DO-214AC (SMA)



### **Mounting Pad Layout**





# **Legal Disclaimer Notice**

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